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## ARTICLE

# Heterogeneous In/Mo cooperative bandgap engineering for promoting visible-light-driven CO<sub>2</sub> photoreduction

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Improving the low charge separation efficiency, poor light absorption capacity, and insufficient active sites of photocatalysts are the important challenges for CO<sub>2</sub> photoreduction. In this study, Mo modified InOOH/In(OH)<sub>3</sub> heterojunction with enhanced CO<sub>2</sub> reduction efficiency was synthesized in situ by using an In(OH)<sub>3</sub> monatomic lamellar material with isolated In atom sites exposed on its surface. And bandgap tuning via the energy levels formed by Mo doping and vacancy defect engineering can simultaneously improve visible light absorption and photogenerated charge separation. The results of experimental characterization and DFT calculation show that the Mo impurity energy levels, O defect energy levels, and surface Mo atoms existing in the InOOH phase can act as an electron transfer ladder in cooperation with the In defect energy levels in the In(OH)<sub>3</sub> phase, thereby promoting electron transfer between heterogeneous interfaces. Under visible light irradiation, the evolution rate of CH<sub>4</sub> and CO of the Mo modified InOOH/In(OH)<sub>3</sub> photocatalyst are more than ~11 and ~8 times higher than those of InOOH, respectively. This work provides new insights into the design of the CO<sub>2</sub> photoreduction platform through a collaborative strategy of bandgap tuning, transition metal doping, and heterostructure construction.

## 1. Introduction

Industrial development has promoted the progress of human society, but it has also produced many negative effects. The use of fossil fuels not only accelerated the energy shortage but also significantly increased CO<sub>2</sub> emissions, causing many serious environmental problems including the greenhouse effect.<sup>1-3</sup> Therefore, the effective catalytic reduction of CO<sub>2</sub> into value-added products plays an indispensable role in alleviating energy and environmental issues.<sup>4-8</sup> In recent years, various strategies including photocatalytic reduction, electrochemical reduction, and photoelectrochemical reduction have been widely used in CO<sub>2</sub> conversion.<sup>9-13</sup> Among them, photocatalytic CO<sub>2</sub> reduction, which uses abundant and sustainable solar energy to mimic natural photosynthesis, has received increasing attention.<sup>14-18</sup> Although a variety of semiconductor photocatalysts have been developed, most of them still have low photocatalytic activity, low conversion efficiency, and low light utilization, which greatly limit possible practical applications. Therefore, the development of excellent photocatalysts is still the key requirement for developing actual CO<sub>2</sub> conversion processes.

Generally, the CO<sub>2</sub> photoreduction reaction mainly includes light absorption, photo-generated electron-hole separation,

and photo-excited electron reduction of CO<sub>2</sub>.<sup>19-21</sup> Although some excellent semiconductor catalysts, such as g-C<sub>3</sub>N<sub>4</sub>,<sup>22,23</sup> TiO<sub>2</sub>,<sup>24,25</sup> CdS,<sup>26,27</sup> and BiVO<sub>4</sub>,<sup>28,29</sup> have been developed, the poor optical absorption capacity, high recombination rate of photogenerated electron-hole pairs, lack of active sites and low stability are still urgent scientific problems to be solved. In recent years, the advent of single-atom catalysts broke through the bottleneck of the development of traditional heterogeneous photocatalytic systems. Due to the unique electronic structure, highly uniform active center and adjustable coordination environment, and other special characteristics, the single-atom catalysts exhibit excellent catalytic activity.<sup>30-34</sup> Although strategies such as atom doping,<sup>35,36</sup> defect engineering,<sup>37-39</sup> and heterostructure construction<sup>40-43</sup> have greatly broadened the development of photocatalysts, it is still very challenging to achieve multi-method fusion to effectively improve photocatalytic activity on this basis.

As a kind of important semiconductor material, indium-based semiconductor nanomaterials (In<sub>2</sub>O<sub>3</sub>, In(OH)<sub>3</sub>, InOOH, In<sub>2</sub>S<sub>3</sub>, InN, etc.) have been widely concerned, which are widely used in the fields of optoelectronics, gas sensing, and catalysis.<sup>44-47</sup> The indium-based hydroxide is rich in hydroxyl groups, which will help activate water molecules to promote catalytic reactions in the water phase.<sup>48,49</sup> However, the hydroxy-rich In(OH)<sub>3</sub> and InOOH, as wide bandgap semiconductors, are generally unable to absorb visible light, which will limit their applications in the field of CO<sub>2</sub> photoreduction.<sup>50-52</sup> It is noteworthy that InOOH as a catalyst for photocatalytic CO<sub>2</sub> reduction has been rarely reported. Therefore, by appropriate modification engineering to adjust the band structure, promote visible light absorption, and achieve effective electron-hole

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separation, they will surely become promising visible light-responsive photocatalysts.

In this research, we synthesized a two-dimensional  $\text{In}(\text{OH})_3$  monatomic lamellar material with highly isolated In atom active sites for the first time. And then, Mo modified  $\text{In}(\text{OH})_3$  atomic-layer-based  $\text{InOOH}$  composite photocatalyst was prepared by in-situ synthesis methods. In this composite system, impurity and defect energy levels were introduced into the bandgap by Mo doping and In/O defects to promote visible light absorption and charge separation. The photocatalytic reaction results show that  $\text{CO}_2$  can be effectively reduced to  $\text{CO}$  and  $\text{CH}_4$  in the pure water system without any sacrificial agents, which indicates that the as-prepared photocatalysts involve two-electron reduction and eight-electron reduction behaviors in the photoreduction process. Compared with  $\text{InOOH}$ , the  $\text{CH}_4$  and  $\text{CO}$  yields of the Mo modified  $\text{InOOH}/\text{In}(\text{OH})_3$  were increased by  $\sim 11$  times and  $\sim 8$  times, respectively. A series of experimental results and theoretical calculations show that the coordinated system of surface Mo atoms, Mo impurity energy levels, and In/O defect energy levels can be used as an electron transfer ladder to promote electron transfer from  $\text{InOOH}$  to  $\text{In}(\text{OH})_3$ . This work provides a new idea for designing a highly active and wide bandgap semiconductor composite photocatalytic system with an excellent visible light response.

## 2. Experimental

The chemicals, characterization details and computational details are shown in Electronic Supplementary Information (ESI)†.

**Synthesis of  $\text{In}(\text{OH})_3$  and  $\text{InOOH}$ .**  $\text{NaOH}$  (1.00 g), deionized water (8 mL), ethanol (8 mL), and oleic acid (10 mL) were successively added into a beaker under constant stirring. Afterward,  $\text{In}(\text{NO}_3)_3$  aqueous solution (2 mL, 0.5 mol/L) was slowly dropped into the beaker. After stirring for 60 min, the colloidal solution was transferred into a 50 mL Teflon-lined autoclave and subjected to hydrothermal treatment at 200 °C for 12 h. After the reaction, the obtained white precipitations were washed with cyclohexane and ethanol and then dried at 60 °C in an oven for 12 h. Finally, the white  $\text{In}(\text{OH})_3$  powder was obtained. For the synthesis of  $\text{InOOH}$ , the volumes of deionized water and oleic acid in the initial reactants are changed to 11 and 13 mL, respectively, and the white  $\text{InOOH}$  powder was obtained.

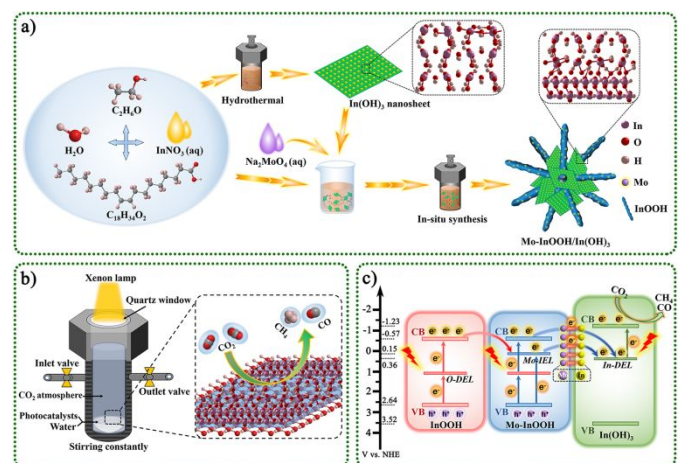
**Synthesis of  $\text{InOOH}/\text{In}(\text{OH})_3$  and Mo-doped  $\text{InOOH}/\text{In}(\text{OH})_3$  heterojunction.** For the synthesis of  $\text{InOOH}/\text{In}(\text{OH})_3$  heterojunction,  $\text{NaOH}$  (1.00 g), deionized water (11 mL), ethanol (8 mL), and oleic acid (13 mL) were successively added into a beaker under constant stirring. Under the condition of stirring, a certain quality of  $\text{In}(\text{OH})_3$  powder was fully dispersed in the above-mixed solution. Then, 2 mL  $\text{In}(\text{NO}_3)_3$  aqueous solution (0.5 mol/L) was slowly added dropwise to the mixed solution. The other experimental procedures are consistent with the synthesis of  $\text{InOOH}$ . According to the theoretical mass percentage (10 wt.%, 20 wt.%, and 30 wt.%) of  $\text{In}(\text{OH})_3$  added, the obtained products were named  $\text{IOOH}/\text{IOH-10}$ ,  $\text{IOOH}/\text{IOH-20}$ , and  $\text{IOOH}/\text{IOH-30}$  respectively. For the synthesis of Mo-

doped  $\text{InOOH}/\text{In}(\text{OH})_3$  heterojunction, the previous synthesis steps are the same as those of  $\text{InOOH}/\text{In}(\text{OH})_3$ , except that 1.97 mL  $\text{In}(\text{NO}_3)_3$  aqueous solution (0.5 mol/L) and 0.03 mL  $\text{Na}_2\text{MoO}_4$  aqueous solution (0.5 mol/L) were slowly added dropwise to the mixed solution of  $\text{NaOH}$  (1.00 g), deionized water (11 mL), ethanol (8 mL), oleic acid (13 mL), and the theoretical mass percentage of 20 wt.%  $\text{In}(\text{OH})_3$ . The obtained product was named  $\text{Mo-IOOH}/\text{IOH-20}$ .

## 3. Results and discussion

### 3.1. Design scheme of overall work

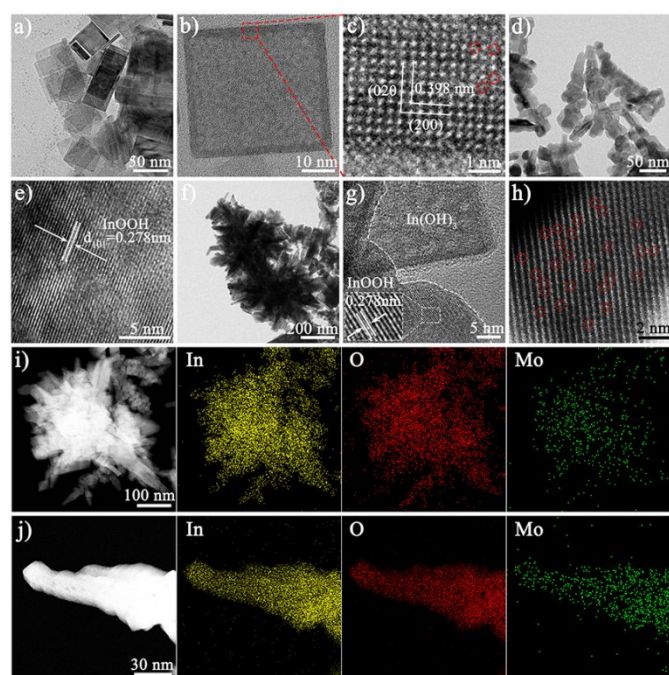
The overall design route of the work was shown in Scheme 1. In this study, we constructed a novel Mo modified  $\text{InOOH}/\text{In}(\text{OH})_3$  heterojunction photocatalyst based on the unique advantages of transition metal element doping, two-dimensional thin-layer materials, defective semiconductor materials, and heterostructures. Specifically,  $\text{In}(\text{OH})_3$  monatomic lamellar material with isolated In atom active sites and In vacancy defects were prepared by a simple hydrothermal method. Further, the obtained  $\text{In}(\text{OH})_3$  nanosheets and related reactants were added to the reactor to obtain Mo modified  $\text{InOOH}/\text{In}(\text{OH})_3$  heterojunction photocatalyst by in-situ synthesis.



**Scheme 1.** (a) Synthesis diagrams of Mo modified  $\text{InOOH}/\text{In}(\text{OH})_3$ . (b) Schematic diagram of the  $\text{CO}_2$  photo-reaction system. (c) The proposed mechanism diagram of photocatalysis under visible-light irradiation ( $\lambda > 420$  nm).

The schematic diagram of the reaction system for photocatalytic reduction of  $\text{CO}_2$  is shown in Scheme 1b. The  $\text{CO}_2$  photoreduction reaction process of the as-prepared photocatalyst took place in a closed reactor with a  $\text{CO}_2$  atmosphere and pure water system. Under the light irradiation with a xenon lamp as the light source, the reduction products of  $\text{CO}_2$  were mainly  $\text{CO}$  and  $\text{CH}_4$ . Here, we proposed a feasible photocatalytic mechanism, as shown in Scheme 1c. Under visible light irradiation ( $\lambda > 420$  nm), photocatalytic activity is achieved through a multi-level electron transfer mechanism. The presence of oxygen defect energy level (O-DEL), Mo impurity energy level (Mo-IEL), and In defect energy level (In-DEL) narrows the energy bandgap. First, the initial electrons are

excited from the valence band (VB) of InOOH to the O-DEL and the Mo-IEL. Then the excited electrons located at the Mo-IEL are further transferred to the In-DEL of the In(OH)<sub>3</sub>. It is further excited to the conduction band (CB) of In(OH)<sub>3</sub> by absorbing photons, and finally, a CO<sub>2</sub> reduction reaction occurs. In addition, the excited electrons of the O-DEL can be transferred to the CB by absorbing photons and then transferred to the Mo-IEL or the In-DEL. The Mo doping strategy can not only introduce impurity energy levels but also form surface Mo atoms to promote charge transfer between interfaces. Therefore, the excellent charge separation efficiency, efficient interfacial charge transfer, and isolated In atom active sites on the surface of In(OH)<sub>3</sub> will surely enable the designed photocatalysts to have excellent catalytic activity.

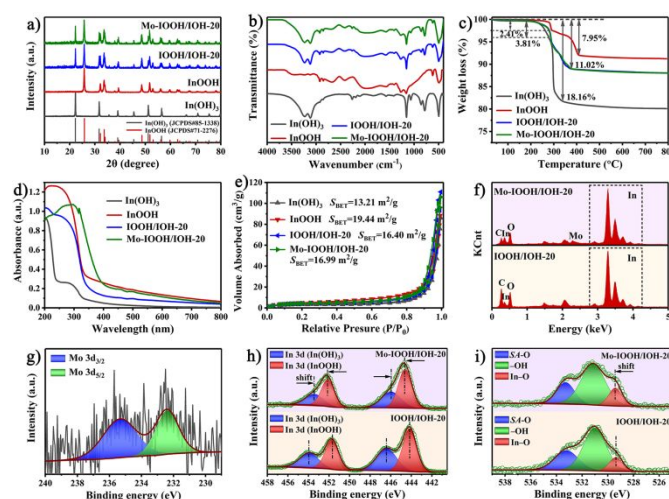


**Fig. 1** (a-c) TEM and HRTEM images of In(OH)<sub>3</sub>. (d,e) TEM and HRTEM images of InOOH. (f-h) TEM, HRTEM, and AC HAADF-STEM images of Mo-IOOH/IOH-20. (i,j) The HAADF-STEM image and EDX elemental mappings of Mo-IOOH/IOH-20 with low magnification and high magnification, respectively.

### 3.2. Morphology properties and structure analysis

The morphology of the as-synthesized photocatalysts can be visualized by using an electron microscope. The scanning electron microscopy (SEM), transmission electron microscopy (TEM), and high-resolution transmission electron microscope (HRTEM) images of In(OH)<sub>3</sub> show the morphology of regular two-dimensional square flakes, as shown in Fig. 1(a-c) and Fig. S1†. More importantly, it can be seen from the high-magnification TEM image (Fig. 1c) that the surface of the In(OH)<sub>3</sub> sheet exposes abundant isolated In atom sites. And the observed lattice spacing of 0.398 nm corresponds to the (020) or (200) crystal plane spacing of In(OH)<sub>3</sub>. In addition, the In vacancy defects marked by red circles can also be observed on the surface of In(OH)<sub>3</sub> nanosheets, which will also be further studied by UV-vis diffuse reflectance spectra and

photoluminescence spectra. InOOH photocatalysts exhibit an irregular rod-like morphology, as shown in Fig. 1(d,e) and Fig. S2†. The HRTEM images of InOOH photocatalysts show a lattice spacing of 0.278 nm, which can be assigned to the (101) crystal plane. The element mapping image shows that In and O elements are uniformly distributed on the surface of InOOH nanorods (Fig. S3†). As shown in Fig. 1(f,g), the Mo-IOOH/IOH-20 composite photocatalysts with the flower-like composite cluster structure have observed In(OH)<sub>3</sub> and InOOH two-phase materials under the high magnification field of view. Aberration-corrected high-angle annular dark-field scanning transmission electron microscopy (AC HAADF-STEM) results confirmed the existence of Mo single-atom sites in the InOOH/In(OH)<sub>3</sub> heterojunction photocatalysts (Fig. 1h). Both the low-magnification and high-magnification element mapping images further confirmed that the Mo elements are uniformly distributed on the surface of the photocatalysts, as shown in Fig. 1(i,g).



**Fig. 2** (a) XRD patterns, (b) FT-IR spectra, (c) TGA curves, (d) UV-vis diffuse reflectance spectra, and (e) N<sub>2</sub> adsorption-desorption isotherms of In(OH)<sub>3</sub>, InOOH, IOOH/IOH-20, and Mo-IOOH/IOH-20. (f) EDS spectra of IOOH/IOH-20 and Mo-IOOH/IOH-20. (g) XPS spectrum for Mo-IOOH/IOH-20 in the region of Mo 3d. (h,i) XPS spectra for IOOH/IOH-20 and Mo-IOOH/IOH-20 in regions of In 3d and O 1s.

Next, the structure of the as-synthesized photocatalysts was studied. The powder X-ray diffraction (XRD) analysis results show that pure cubic phase In(OH)<sub>3</sub> and orthorhombic phase InOOH have been obtained. And the XRD spectra of IOOH/IOH-*x* (*x* = 10, 20, and 30) and Mo-IOOH/IOH-20 composite photocatalysts show the diffraction peaks of In(OH)<sub>3</sub> and InOOH simultaneously, indicating the coexistence of the two phases (Fig. 2a and Fig. S4†). Especially, no new diffraction peaks are introduced after Mo doping, indicating that Mo doping does not change the product's crystal phase.

The FT-IR spectra of In(OH)<sub>3</sub> and InOOH both reveal typical characteristic absorption peaks. As shown in Fig. 2b, the characteristic absorption peaks located at 3230 cm<sup>-1</sup> (O–H stretching vibrations), 1155 cm<sup>-1</sup> (O–H bending vibration), 780 cm<sup>-1</sup> (O–H bending vibration), and 494 cm<sup>-1</sup> (In–OH absorption

bands) can be attributed to the functional groups of  $\text{In}(\text{OH})_3$ . And the characteristic absorption peaks attributed to  $\text{InOOH}$  are located at  $2924\text{ cm}^{-1}$  ( $-\text{CH}_2$  asymmetric stretching mode),  $2854\text{ cm}^{-1}$  ( $-\text{CH}_2$  symmetric stretching mode),  $1269\text{ cm}^{-1}$  (O–H bending or deformation vibration),  $1160\text{ cm}^{-1}$  (O–H bending or deformation vibration), and  $491\text{ cm}^{-1}$  (In–O vibration), respectively.<sup>52,53</sup> The characteristic peaks attributed to both  $\text{In}(\text{OH})_3$  and  $\text{InOOH}$  were observed for the Mo-IOOH/IOH-20 composite photocatalysts, which further confirmed that the Mo-IOOH/IOH-20 composite photocatalysts have been successfully obtained. The structural information of  $\text{InOOH}$ , IOOH/IOH-20, and Mo-IOOH/IOH-20 was also further investigated by Raman spectrometry (Fig. S5†). The peaks at  $228$ ,  $272$ ,  $316$ , and  $459\text{ cm}^{-1}$  can be assigned to the characteristic vibration modes of  $\text{InOOH}$ . In contrast, the slight shifts in the characteristic peaks of IOOH/IOH-20 and Mo-IOOH/IOH-20 indicate the formation of a heterojunction between  $\text{In}(\text{OH})_3$  and  $\text{InOOH}$ .

The TGA analysis results show that all the  $\text{In}(\text{OH})_3$ ,  $\text{InOOH}$ , IOOH/IOH-20, and Mo-IOOH/IOH-20 samples exhibit excellent thermal stability with no significant weight loss in the range of  $200\text{ }^\circ\text{C}$  (Fig. 2c). The thermal weight loss curve of  $\text{In}(\text{OH})_3$  shows two weight loss steps with a total weight loss of about 18.16%, which can be attributed to the desorption of the surface-adsorbed solvent molecules and dehydration during the transition from  $\text{In}(\text{OH})_3$  to  $\text{In}_2\text{O}_3$ .<sup>48</sup> Similarly, there are two obvious stages of thermal weight loss in  $\text{InOOH}$ . The weight loss in the first and second stages is caused by the desorption of the surface-adsorbed solvent molecules below  $290\text{ }^\circ\text{C}$  and the conversion of  $\text{InOOH}$  to  $\text{In}_2\text{O}_3$  at higher temperatures above  $290\text{ }^\circ\text{C}$ , respectively.<sup>54</sup> The total weight loss of IOOH/IOH-20 and Mo-IOOH/IOH-20 are both about 11.02%, showing a similar thermogravimetric loss process as above.

It can also be seen from the UV-visible absorption curve (Fig. 2d) that the  $\text{InOOH}$  has significant tailing absorption in the wavelength range of  $350\text{--}800\text{ nm}$ , indicating that it has visible light absorption ability. In addition, the  $\text{In}(\text{OH})_3$  photocatalyst exhibits strong absorption bands caused by the In vacancy defect in the wavelength range of  $240\text{--}350\text{ nm}$ , which is similar to the results previously reported.<sup>48,50</sup> It is worth noting that compared with IOOH/IOH-20, the absorption spectrum of Mo-IOOH/IOH-20 photocatalyst is redshifted and its visible absorption capacity is enhanced. The bandgap energies of  $\text{InOOH}$ , IOOH/IOH-20, and Mo-IOOH/IOH-20 are 3.21, 3.30, and 2.60 eV, respectively (Fig. S6†). In particular,  $\text{In}(\text{OH})_3$  has two bandgap energies of 4.75 and 3.16 eV. And the former one can be attributed to the main bandgap from bulk  $\text{In}(\text{OH})_3$ , while later one is created by In vacancy. This is consistent with the previously reported results.<sup>48,50</sup> In addition, UV diffuse reflectance spectra and bandgaps plots of IOOH/IOH-10 and IOOH/IOH-30 are shown in Fig. S7†.

In general, the specific surface area and pore structure of the photocatalyst are positively related to the adsorption performance. Therefore, the physical properties of the specific surface area and pore structure of the prepared series of photocatalysts were studied (Fig. 2e and Fig. S8†). All the four types of  $\text{In}(\text{OH})_3$ ,  $\text{InOOH}$ , IOOH/IOH-20, and Mo-IOOH/IOH-20

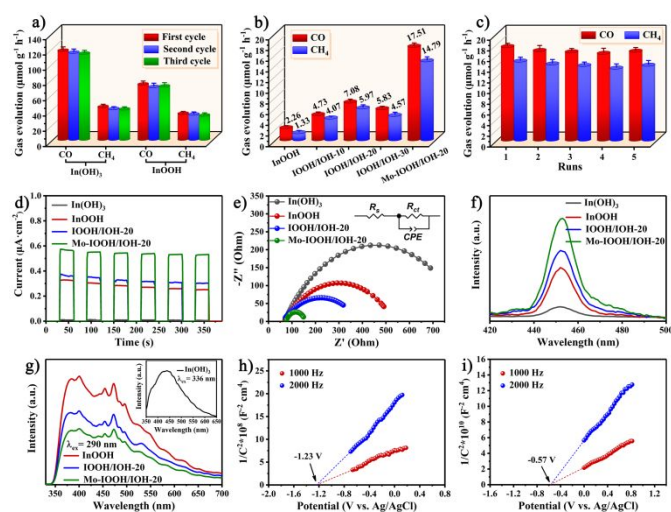
photocatalysts exhibit typical type-IV adsorption-desorption isotherms with obvious hysteresis loops and condensation steps, indicating the existence of mesopores and macropores. The Brunauer–Emmett–Teller (BET) specific surface areas of  $\text{In}(\text{OH})_3$  and  $\text{InOOH}$  photocatalysts are 13.21 and  $19.44\text{ m}^2/\text{g}$ , respectively. The BET-specific surface area of the Mo-IOOH/IOH-20 composite photocatalyst is  $16.99\text{ m}^2/\text{g}$ , which maintains a relatively large specific surface area. Energy dispersive spectrometer (EDS) analysis further explained the elemental composition of the synthesized photocatalysts. The EDS spectrum shows the presence of C, In, O, Mo, Cu, and Al elements in the IOOH/IOH-20 photocatalysts (Fig. 2f). The Cu and Al elements are derived from the sample test carrier. Mo element was also observed on the surface of the Mo-IOOH/IOH-20 composite photocatalysts. The EDS spectra of  $\text{In}(\text{OH})_3$  and  $\text{InOOH}$  are shown in Fig. S9†.

The composition and surface electronic state of the as-synthesized photocatalysts were further explained by X-ray photoelectron spectroscopy (XPS). The XPS survey spectra reveal that all photocatalysts are composed of target elements and C (adventitious carbon) elements (Fig. S10†). The high-resolution Mo 3d spectrum of Mo-IOOH/IOH-20 shows the binding energies of Mo  $3d_{3/2}$  and Mo  $3d_{5/2}$  peaks at 235.3 eV and 232.4 eV, respectively, indicating that Mo mainly exists in the form of +6 (Fig. 2g). The binding energies of In  $3d_{3/2}$  and In  $3d_{5/2}$  are 454.05 eV and 446.50 eV for  $\text{In}(\text{OH})_3$ , 451.70 eV and 444.15 eV for  $\text{InOOH}$ , respectively (Fig. S11† and S12†). As shown in Fig. S11† and S12†, the O1s high-resolution spectra can confirm two types of oxygen species (surface adsorbed oxygen and  $-\text{OH}$ ) for  $\text{In}(\text{OH})_3$ , and three types of oxygen species (surface adsorbed oxygen (SA-O), In–O, and  $-\text{OH}$ ) for  $\text{InOOH}$ , respectively. According to the In 3d spectra of IOOH/IOH-20 and Mo-IOOH/IOH-20 (Fig. 2h), the signal peaks for the  $\text{In}(\text{OH})_3$  phase and the  $\text{InOOH}$  phase can be identified one by one. Among them, the In 3d orbit signal peaks of  $\text{In}(\text{OH})_3$  phase and  $\text{InOOH}$  phase in Mo-IOOH/IOH-20 are shifted by 0.5 eV to low binding energy and 0.45 eV to high binding energy, respectively. Similarly, the In–O oxygen species assigned to the  $\text{InOOH}$  phase are also shifted to higher high binding energies (Fig. 2i). These results indicate that the charge density around the atoms in the  $\text{In}(\text{OH})_3$  phase is increased and the charge density around the atoms in the  $\text{InOOH}$  phase is decreased, implying that electrons can be transferred from  $\text{InOOH}$  to  $\text{In}(\text{OH})_3$ . More importantly, Mo single-atoms can also facilitate the charge transfer between the heterointerfaces, which is consistent with the mechanism mentioned above.

### 3.3. Photocatalytic activity and charge separation

The  $\text{CO}_2$  reduction activity of all the prepared photocatalysts was also evaluated. The prepared photocatalysts were subjected to a  $\text{CO}_2$  photoreduction reaction for 5 hours in a pure water system without using any sacrificial agents. The results show that CO and  $\text{CH}_4$  are the main products of the photocatalytic reaction. As shown in Fig. 3a, both  $\text{In}(\text{OH})_3$  and  $\text{InOOH}$  exhibit highly efficient CO and  $\text{CH}_4$  evolution rates under ultraviolet light irradiation, and the yields hardly changed after three cycles of reaction. Among them, the CO and  $\text{CH}_4$  evolution

rates of  $\text{In}(\text{OH})_3$  photocatalyst are 116.62 and  $42.81 \mu\text{mol g}^{-1} \text{h}^{-1}$ , respectively. In further exploration, the  $\text{CO}_2$  photoreduction ability of  $\text{InOOH}$ ,  $\text{IOOH}/\text{IOH}-x$  ( $x = 10, 20, \text{ and } 30$ ), and  $\text{Mo-IOOH}/\text{IOH}-20$  photocatalysts were evaluated under visible-light irradiation (Fig. 3b). The results demonstrate that the  $\text{CO}$  and  $\text{CH}_4$  evolution rate of  $\text{Mo-IOOH}/\text{IOH}-20$  is 17.51 and  $14.79 \mu\text{mol g}^{-1} \text{h}^{-1}$ , respectively, which are significantly higher than those of  $\text{InOOH}$  and  $\text{IOOH}/\text{IOH}-x$  ( $x = 10, 12, \text{ and } 30$ ). Compared with  $\text{InOOH}$ , the evolution rate of  $\text{CO}$  and  $\text{CH}_4$  over  $\text{Mo-IOOH}/\text{IOH}-20$  were increased by  $\sim 8$  times and  $\sim 11$  times, respectively. The selectivity of  $\text{CO}_2$  photoreduction products of the prepared photocatalysts is shown in Fig. S13<sup>†</sup>. Furthermore, the  $\text{CO}_2$  adsorption capacity of the photocatalysts was further investigated by  $\text{CO}_2$ -TPD experiments (Fig. S14<sup>†</sup>). The results show that  $\text{In}(\text{OH})_3$  exhibits stronger  $\text{CO}_2$  desorption band and surface basic sites in the range of 25–280 °C compared to  $\text{InOOH}$ , which proves that  $\text{In}(\text{OH})_3$  surface has higher  $\text{CO}_2$  adsorption ability. The above results further indicate that the combination of material recombination, dual-single-atom modification, and bandgap tuning is an effective strategy to improve the efficiency of  $\text{CO}_2$  photoreduction. In addition, the evolution rate of  $\text{CO}$  and  $\text{CH}_4$  for  $\text{Mo-IOOH}/\text{IOH}-20$  hardly changed during the five catalytic reactions (Fig. 3c). The structure of the photocatalysts after the catalytic reaction was also studied. The results of the XRD pattern show that there are no other phases or impurities in  $\text{Mo-IOOH}/\text{IOH}-20$  after the reaction, indicating that it maintained excellent structural stability during the reaction (Fig. S15<sup>†</sup>).



**Fig. 3** (a) Production of  $\text{CO}$  and  $\text{CH}_4$  for  $\text{InOOH}$  and  $\text{In}(\text{OH})_3$  under ultraviolet light irradiation. (b) Production of  $\text{CO}$  and  $\text{CH}_4$  for different samples under visible light irradiation. (c) Production of  $\text{CO}$  and  $\text{CH}_4$  for  $\text{Mo-IOOH}/\text{IOH}-20$  in five cycles. (d) Photocurrent-time profiles, (e) Nyquist plots with the equivalent circuit as the insert, (f) Fluorescence spectra related to the produced hydroxyl radicals, and (g) PL spectra of different samples. Mott-Schottky plots of (h)  $\text{In}(\text{OH})_3$  and (i)  $\text{InOOH}$ .

The charge separation efficiency was studied by recording the transient photocurrent response of several on/off cycles under visible light irradiation. As shown in Fig. 3d, the photocurrent of all photocatalysts shows high repeatability and stability in

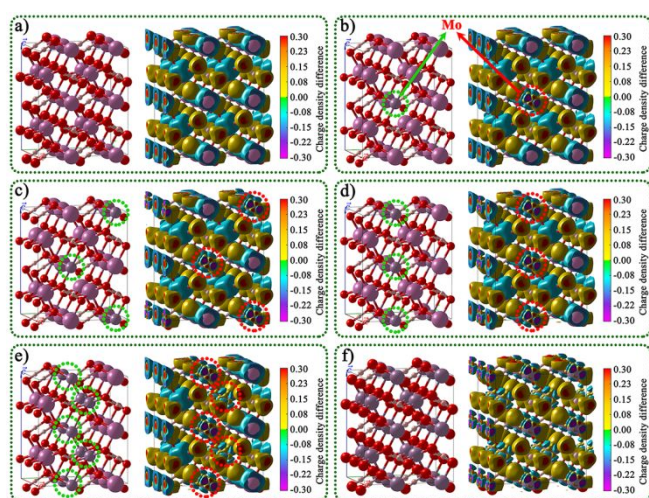
multiple cycles. The  $\text{Mo-IOOH}/\text{IOH}-20$  shows greater photocurrent intensity, further confirming that it has higher photogenerated carrier separation and transfer efficiency. Furthermore, the electrochemical impedance spectroscopy (EIS) and the equivalent circuit diagram obtained by fitting indicate that  $\text{Mo-IOOH}/\text{IOH}-20$  has a smaller semicircle radius and  $R_{ct}$  value compared with  $\text{In}(\text{OH})_3$ ,  $\text{InOOH}$  and  $\text{IOOH}/\text{IOH}-20$  (Fig. 3e and Table S1<sup>†</sup>). These results confirm that the interfacial charge transfer resistance of  $\text{Mo-IOOH}/\text{IOH}-20$  is significantly reduced, which can be inferred that the introduction of  $\text{Mo}$  promotes charge transfer and separation.<sup>55</sup> In further research, the classic coumarin fluorescence was used to detect the amount of hydroxyl radicals ( $\cdot\text{OH}$ ) produced during photochemical processes. As the key active substance, the  $\cdot\text{OH}$  can react with coumarin to generate luminescent 7-hydroxycoumarin in the process of photocatalytic reaction.<sup>19,55</sup> Therefore, the production of  $\cdot\text{OH}$  is directly proportional to the fluorescence signal intensity. As shown in Fig. 3f, the fluorescence spectra test results show that  $\text{Mo-IOOH}/\text{IOH}-20$  has the highest  $\cdot\text{OH}$  yield, which means higher electron-hole pair separation efficiency. The improvement of photogenerated carrier separation and transfer efficiency can be attributed to the existence of the  $\text{Mo}$ -impurity energy levels,  $\text{In}/\text{O}$  defect energy levels, and heterojunction interface.

Room temperature photoluminescence (PL) spectroscopy also further confirmed that  $\text{IOOH}/\text{IOH}-20$  has a higher charge separation efficiency (Fig. 3g). Previous studies have shown that  $\text{In}$  vacancy defects can cause the crystalline  $\text{In}(\text{OH})_3$ , which has no photoluminescence emission, to appear a wide emission peak in the range of about 350 to 750 nm.<sup>47</sup> In this study, we also observed the  $\text{In}$  vacancy defect-states emission in the PL spectrum of  $\text{In}(\text{OH})_3$ . This result further confirms that the absorption peak at around 300 nm in the UV diffuse reflectance spectrum of  $\text{In}(\text{OH})_3$  is caused by  $\text{In}$  vacancy defects. In addition, the two broad emission bands in the range of 350 to 400 nm and 450 to 500 nm can be observed in the PL spectrum of  $\text{InOOH}$ , which can be attributed to intrinsic bandgap transition and oxygen vacancies state, respectively.<sup>48</sup> In addition, Mott-Schottky plots exhibited a positive slope, indicating that  $\text{In}(\text{OH})_3$  and  $\text{InOOH}$  are typical n-type semiconductors (Fig. 3(h,i)). And it can be known that the flat band potentials of  $\text{In}(\text{OH})_3$  and  $\text{InOOH}$  are  $-1.23$  and  $-0.57$  V, respectively, which are equivalent to  $-1.03$  and  $-0.37$  V versus the normal hydrogen electrode (NHE), respectively. It is well known that the CB potentials of n-type semiconductors are about 0.1 or 0.2 V higher than the flat band potentials.<sup>48</sup> Therefore, the CB potentials of  $\text{In}(\text{OH})_3$  and  $\text{InOOH}$  are  $-1.23$  and  $-0.57$  V versus the NHE, respectively.

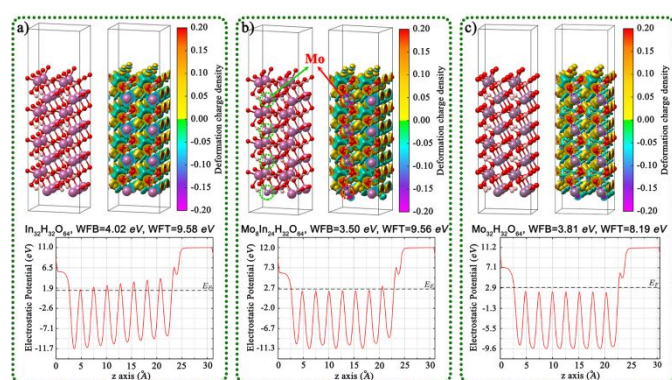
### 3.4. DFT calculation

The rationality of the designed charge separation system was further studied theoretically by using density functional theory (DFT). The geometric structures, charge density difference, and electron localization function of  $\text{In}_{16}\text{H}_{16}\text{O}_{32}$ ,  $\text{MoIn}_{15}\text{H}_{16}\text{O}_{32}$ ,  $\text{Mo}_2\text{In}_{14}\text{H}_{16}\text{O}_{32}$ ,  $\text{Mo}_4\text{In}_{12}\text{H}_{16}\text{O}_{32}$ ,  $\text{Mo}_8\text{In}_8\text{H}_{16}\text{O}_{32}$ , and  $\text{Mo}_{16}\text{H}_{16}\text{O}_{32}$  are shown in Fig. 4 and Fig. S16<sup>†</sup>. It is noted that the yellow area indicates gaining electrons, on the contrary, the blue area indicates losing electrons. Charge analysis showed that the net

charge on In and Mo is 1.974260 and 1.863416, respectively. This indicates that the In is more easily to lose electrons than that of Mo. That leads to the electron density around Mo being larger than that around In. The bond order of In and Mo is 2.847246 and 2.216849, respectively. This indicates that Mo–O bond strength is larger than that of In–O. The theoretical simulation of band structure and density of states for  $\text{In}_{16}\text{H}_{16}\text{O}_{32}$ ,  $\text{MoIn}_{15}\text{H}_{16}\text{O}_{32}$ ,  $\text{Mo}_2\text{In}_{14}\text{H}_{16}\text{O}_{32}$ ,  $\text{Mo}_4\text{In}_{12}\text{H}_{16}\text{O}_{32}$ ,  $\text{Mo}_8\text{In}_8\text{H}_{16}\text{O}_{32}$ , and  $\text{Mo}_{16}\text{H}_{16}\text{O}_{32}$  are shown in Fig. S17†. It is noted that the differences of the six configurations are not only due to the Mo content but also due to the position of Mo replacing In. And thus, the results indicated that the bandgap is not only related to the doping amount of Mo but also related to the position where Mo replaces In. Overall, the bandgap of  $\text{Mo}_x\text{In}_{16-x}\text{H}_{16}\text{O}_{32}$  ( $x = 0, 1, 2, 4, 8, \text{ and } 16$ ) increases with the increase of Mo content due to the larger bond strength of the M–O bond than that of the In–O bond.



**Fig. 4** Geometric structures and the corresponding charge density difference of (a)  $\text{In}_{16}\text{H}_{16}\text{O}_{32}$ , (b)  $\text{MoIn}_{15}\text{H}_{16}\text{O}_{32}$ , (c)  $\text{Mo}_2\text{In}_{14}\text{H}_{16}\text{O}_{32}$ , (d)  $\text{Mo}_4\text{In}_{12}\text{H}_{16}\text{O}_{32}$ , (e)  $\text{Mo}_8\text{In}_8\text{H}_{16}\text{O}_{32}$ , and (f)  $\text{Mo}_{16}\text{H}_{16}\text{O}_{32}$ .

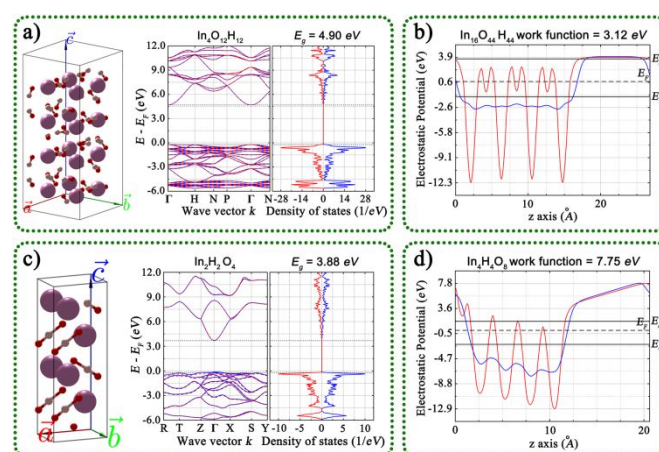


**Fig. 5** Geometric structures, charge density difference, calculated Fermi levels, and work functions of the (001) surface of (a)  $\text{In}_{32}\text{H}_{32}\text{O}_{64}$ , (b)  $\text{Mo}_8\text{In}_{24}\text{H}_{32}\text{O}_{64}$ , and (c)  $\text{Mo}_{32}\text{H}_{32}\text{O}_{64}$ .

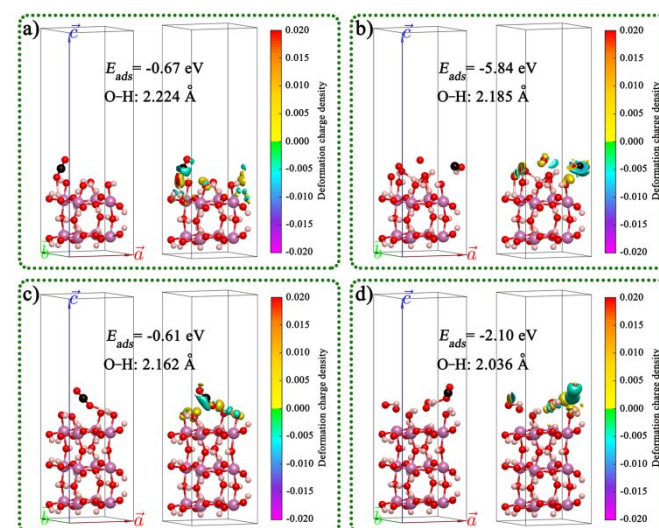
The geometric structures, charge density difference, calculated Fermi levels, and work functions of the (001) surface of  $\text{Mo}_x\text{In}_{32-x}\text{H}_{32}\text{O}_{64}$  ( $x = 0, 2, 4, 8, 16, \text{ and } 32$ ) with different Mo doping amounts and different exposed atoms are shown in Fig.

5 and Fig. S18†. For  $\text{In}_{32}\text{H}_{32}\text{O}_{64}$ ,  $\text{Mo}_8\text{In}_{24}\text{H}_{32}\text{O}_{64}$ , and  $\text{Mo}_{32}\text{H}_{32}\text{O}_{64}$  in Fig. 5, the exposed atoms are mainly O, and the work function value decreases with the increase of Mo content. For  $\text{Mo}_2\text{In}_{30}\text{H}_{32}\text{O}_{64}$ ,  $\text{Mo}_4\text{In}_{28}\text{H}_{32}\text{O}_{64}$ , and  $\text{Mo}_{16}\text{In}_{16}\text{H}_{32}\text{O}_{64}$  in Fig. S18†, the exposed atoms are mainly In and Mo, and the work function value also decreases with the increase of Mo content. After doping Mo single atom, the reduction of surface work function values is conducive to the migration of electrons from the interior to the surface, which is conducive to the improvement of photocatalytic performance.

We also compared the geometric structures, work functions, band structure (BS), and density of states (DOS) of the (001) surface for  $\text{InOOH}$  and  $\text{In}(\text{OH})_3$ , as shown in Fig. 6. The theoretical band gaps of  $\text{InOOH}$  and  $\text{In}(\text{OH})_3$  are separately 4.90 and 3.88 eV, and the work function values are 3.12 and 7.75 eV for  $\text{InOOH}$  and  $\text{In}(\text{OH})_3$ , respectively. This result further proves that electrons tend to transfer from  $\text{InOOH}$  to  $\text{In}(\text{OH})_3$  inside  $\text{InOOH}/\text{In}(\text{OH})_3$  heterojunction.



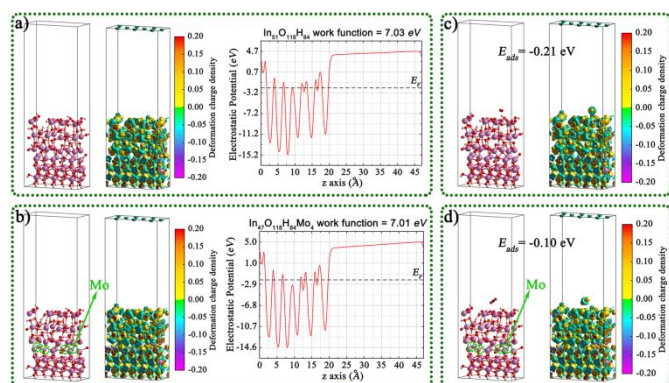
**Fig. 6** Geometric structures, band structure, the density of states, and calculated work functions of the (001) surface for (a,b)  $\text{InOOH}$  and (c,d)  $\text{In}(\text{OH})_3$ .



**Fig. 7**  $\text{CO}_2$  adsorbed on the (001) surface of  $\text{In}(\text{OH})_3$  with different section thicknesses, exposed atoms, and adsorption sites: (a)  $\text{In}_8\text{CO}_{26}\text{H}_{24}$ , (b)  $\text{In}_8\text{CO}_{30}\text{H}_{28}$ , (c)  $\text{In}_{12}\text{CO}_{38}\text{H}_{36}$ , and (d)  $\text{In}_{12}\text{CO}_{40}\text{H}_{40}$ .

The geometric structures, charge density difference, calculated Fermi levels, and work functions of the (001) surface of InOOH with different section thicknesses and different exposed atoms are shown in Fig. S19<sup>†</sup>. The results indicated that the Fermi levels, and work functions values are related to the section thicknesses and different exposed atoms. The CO<sub>2</sub> adsorbed on the (001) surface of In(OH)<sub>3</sub> and InOOH with different section thicknesses, exposed atoms, and adsorption sites was also studied, as shown in Fig. 7 and Fig. S20<sup>†</sup>. The results indicated that the adsorption energies ( $E_{ads}$ ) of CO<sub>2</sub> on the In(OH)<sub>3</sub> (001) surface were much larger than those on the InOOH (001) surface. This indicates that CO<sub>2</sub> will be preferentially adsorbed on the surface of In(OH)<sub>3</sub>. This result is consistent with the test results of CO<sub>2</sub>-TPD mentioned above.

In order to further study the interfacial electron transport between In(OH)<sub>3</sub> and InOOH, the InOOH/In(OH)<sub>3</sub> and Mo doped InOOH/In(OH)<sub>3</sub> heterojunction were constructed and the  $E_{ads}$  of CO<sub>2</sub> on the (001) surface of heterojunction were also calculated theoretically, as shown in Fig. 8. After Mo doping, the work function decreases slightly, which is more conducive to the transmission of electrons to the surface. In addition, the CO<sub>2</sub> adsorption energy is reduced.



**Fig. 8** Geometric structures, charge density difference, calculated work functions, and CO<sub>2</sub> adsorbed on the (001) surface for (a,c) InOOH/In(OH)<sub>3</sub> and (b,d) Mo doped InOOH/In(OH)<sub>3</sub> heterojunction.

The optical properties of In<sub>4</sub>O<sub>12</sub>H<sub>12</sub>, In<sub>2</sub>H<sub>2</sub>O<sub>4</sub>, and Mo<sub>x</sub>In<sub>16-x</sub>H<sub>16</sub>O<sub>32</sub> ( $x = 0, 1, 2, 4, 8, \text{ and } 16$ ) such as absorption coefficient, dielectric function, extinction coefficient, refractive index, reflectance, and optical conductivity were calculated by using DFT, as shown in Fig. S21<sup>†</sup> and Fig. S22<sup>†</sup>. The calculated results of In<sub>4</sub>O<sub>12</sub>H<sub>12</sub>, In<sub>2</sub>H<sub>2</sub>O<sub>4</sub>, and Mo<sub>x</sub>In<sub>16-x</sub>H<sub>16</sub>O<sub>32</sub> ( $x = 0, 1, 2, 4, 8, \text{ and } 16$ ) show that they have significant differences in optical properties. More importantly, Mo doping has a positive effect on improving the optical properties of materials, which is an effective method to tune the optical properties of materials. This is consistent with the results of absorption spectra and band structures discussed above. Therefore, the optical properties of photocatalysts can be adjusted by Mo doping to achieve the purpose of improving photocatalytic activity.

## 4. Conclusions

In summary, an In(OH)<sub>3</sub> monatomic lamellar material with isolated In atom sites exposed on its surface was successfully

synthesized, which not only has high-efficiency photocatalytic performance, but also can be combined with InOOH to in-situ prepare Mo modified InOOH/In(OH)<sub>3</sub> heterojunction photocatalyst with visible-light response. And we also confirmed that bandgap tuning by introducing impurity levels and defect levels is a feasible strategy to improve visible light absorption and charge separation efficiency. The results show that the visible-light CO<sub>2</sub> reduction efficiency of Mo-IOOH/IOH-20 (17.51  $\mu\text{mol g}^{-1} \text{h}^{-1}$  for CO and 14.79  $\mu\text{mol g}^{-1} \text{h}^{-1}$  for CH<sub>4</sub>) is much higher than that of InOOH (2.26  $\mu\text{mol g}^{-1} \text{h}^{-1}$  for CO and 1.33  $\mu\text{mol g}^{-1} \text{h}^{-1}$  for CH<sub>4</sub>), and the evolution rate of CO and CH<sub>4</sub> was increased by  $\sim 8$  times and  $\sim 11$  times, respectively. The results of XPS characterization and charge density difference obtained by DFT calculation show that the charge density around the atoms in the In(OH)<sub>3</sub> phase is increased and the charge density around the atoms in the InOOH phase is decreased, implying that electrons can be transferred from InOOH to In(OH)<sub>3</sub>. In brief, not only the Mo impurity energy levels, O defect energy levels, and surface atoms exist in the InOOH phase, but also the In defect energy levels exist in the In(OH)<sub>3</sub> phase, which works together to act as electron transfer ladder, thereby promoting the efficiency of charge separation and transfer between heterogeneous interfaces and enhancing the CO<sub>2</sub> photoreduction efficiency. This work provides a new way for the rational design of CO<sub>2</sub> photoreduction catalysts with high catalytic activity.

## Author contributions

Guoyang Gao: Experimental, Conceptualization, Methodology, Formal analysis, Investigation, Data curation, Writing – original draft. Qiuye Wang: Experimental, Formal analysis. Peifen Zhu: Conceptualization, Methodology, Formal analysis, Data curation, Writing – review and editing, Resources, Software. Hongyang Zhu: Formal analysis, Writing – review and editing, Resources. Yang Qu: Methodology, Formal analysis, Writing – review and editing. Guofeng Wang: Conceptualization, Methodology, Formal analysis, Investigation, Writing – review and editing, Supervision, Resources.

## Conflicts of interest

There are no conflicts to declare.

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